

BAT60B

SCHOTTKY BARRIER DIODE

FEATURES

- High Current Rectifier Schottky Diode with Low V_F Drop
- Low Voltage, Low Inductance
- For Power Supply
- For Detection and Step-up-Conversion







MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _R	DC Blocking Voltage	10	V	
I _F	Forward Current	3	А	
I _{FSM}	Non-repetitive Peak Forward Surge Current @t=8.3ms	5		
P_{D}	Power Dissipation	350	mW	
R _{0JA}	Thermal Resistance from Junction to Ambient	286	°C/W	
Tj	Operating Junction Temperature Range	-40 ~ +125	$^{\circ}$	
T_{stg}	Storage Temperature Range	- 55 ~ + 150	$^{\circ}$	

ELECTRICAL CHARACTERISTICS(Ta=25℃ unless otherwise specified)

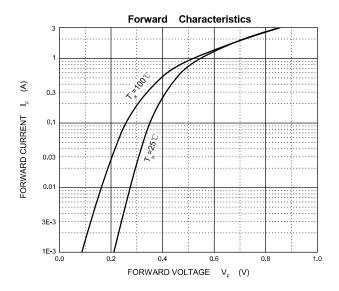
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Reverse voltage	$V_{(BR)}$	I _R =1mA	10			٧
	I _R	V _R =5V			15	μΑ
Reverse current		V _R =8V			25	μΑ
	V _F	I _F =100mA			0.38	V
Forward voltage		I _F =500mA			0.5	
		I _F =1000mA			0.6	
Total capacitance	C_{tot}	V _R =5V,f=1MHz		30		pF

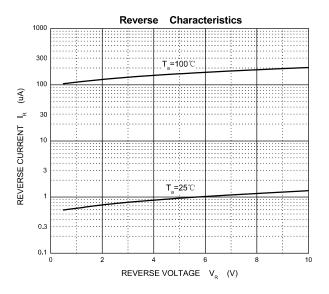


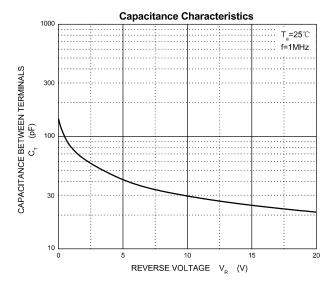
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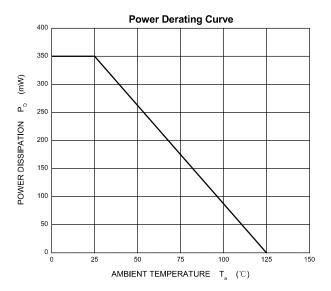
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Typical Characteristics







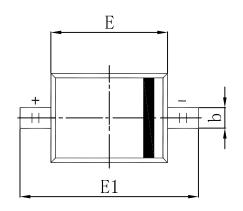


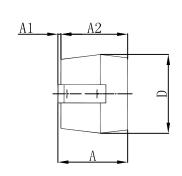


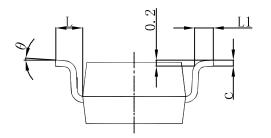
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SCHOTTKY BARRIER DIODE

SOD-323 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α		1.100		0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.500	2.750	0.098	0.108	
L	0.475 REF		0.019 REF		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	